

CMST3410 NPN  
 CMST7410 PNP  
 SURFACE MOUNT  
 SUPERmini™  
 COMPLEMENTARY SILICON  
 LOW  $V_{CE(SAT)}$  TRANSISTORS

SUPERmini™



SOT-323 CASE

# Central™

Semiconductor Corp.

## DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMST3410, CMST7410 types are complementary silicon transistors manufactured by the epitaxial planar process, epoxy molded in a SUPERmini™ surface mount package, designed for battery driven, handheld devices requiring high current and low  $V_{CE(SAT)}$  voltages.

## MARKING CODES:

CMST3410: C03

CMST7410: C07

## MAXIMUM RATINGS: ( $T_A=25^\circ\text{C}$ )

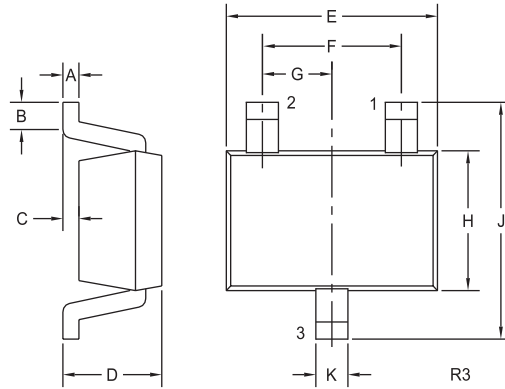
	SYMBOL		UNITS
Collector-Base Voltage	$V_{CBO}$	40	V
Collector-Emitter Voltage	$V_{CEO}$	25	V
Emitter-Base Voltage	$V_{EBO}$	6.0	V
Collector Current	$I_C$	1.0	A
Collector Current (Peak)	$I_{CM}$	1.5	A
Power Dissipation	$P_D$	275	mW
Operating and Storage			
Junction Temperature	$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$
Thermal Resistance	$\theta_{JA}$	455	$^\circ\text{C/W}$

## ELECTRICAL CHARACTERISTICS: ( $T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	CMST3410		CMST7410	MAX	UNITS
			TYP	TYP			
$I_{CBO}$	$V_{CB}=40\text{V}$					100	nA
$I_{EBO}$	$V_{EB}=6.0\text{V}$					100	nA
$BV_{CBO}$	$I_C=100\mu\text{A}$	40					V
$BV_{CEO}$	$I_C=10\text{mA}$	25					V
$BV_{EBO}$	$I_E=100\mu\text{A}$	6.0					V
$V_{CE(SAT)}$	$I_C=50\text{mA}, I_B=5.0\text{mA}$		20	25	50		mV
$V_{CE(SAT)}$	$I_C=100\text{mA}, I_B=10\text{mA}$		35	40	75		mV
$V_{CE(SAT)}$	$I_C=200\text{mA}, I_B=20\text{mA}$		75	80	150		mV
$V_{CE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$		130	150	250		mV
$V_{CE(SAT)}$	$I_C=800\text{mA}, I_B=80\text{mA}$		200	220	400		mV
$V_{CE(SAT)}$	$I_C=1.0\text{A}, I_B=100\text{mA}$		250	275	450		mV
$V_{BE(SAT)}$	$I_C=800\text{mA}, I_B=80\text{mA}$				1.1		V
$V_{BE(ON)}$	$V_{CE}=1.0\text{V}, I_C=10\text{mA}$				0.9		V
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=10\text{mA}$	100					
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=100\text{mA}$	100			300		
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=500\text{mA}$	100					
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=1.0\text{A}$	50					
$f_T$	$V_{CE}=10\text{V}, I_C=50\text{mA}, f=100\text{MHz}$	100					MHz
$C_{ob}$	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$ (CMST3410)					10	pF
$C_{ob}$	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$ (CMST7410)					15	pF

R0 (5-April 2005)

**SOT-323 CASE - MECHANICAL OUTLINE**



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.002	0.008	0.05	0.20
B	0.004	-	0.10	-
C	-	0.004	-	0.10
D	0.031	0.043	0.80	1.10
E	0.071	0.087	1.80	2.20
F	0.051		1.30	
G	0.026		0.65	
H	0.045	0.053	1.15	1.35
J	0.079	0.087	2.00	2.20
K	0.008	0.016	0.20	0.40

SOT-323 (REV: R3)

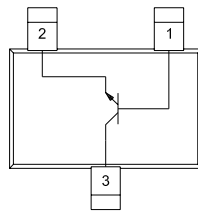
**LEAD CODE:**

- 1) BASE
- 2) EMITTER
- 3) COLLECTOR

**MARKING CODES:**

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CMST7410: C07

**CMST3410 NPN**



**LEAD CODE:**

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**CMST7410 PNP**

